# Security on Plastics: Fake or Real?

Nele Mentens KU Leuven, imec-COSIC/ESAT

Joint work with Jan Genoe, Thomas Vandenabeele, Lynn Verschueren, Dirk Smets, Wim Dehaene, Kris Myny KU Leuven & IMEC

> CROSSING conference September 9, 2019, Darmstadt, Germany

## Outline

- Flexible electronics on plastics
- Challenge #1: crypto core on plastics
- Challenge #2: key hiding
- Remaining challenges
- Conclusion

### Flexible electronics on plastics Displays

- Widespread commercial use in flexible displays
- Millions of thin-film transistors controlling the pixels



CROSSING, 2019, Darmstadt, Germany

### Flexible electronics on plastics Digital circuits

- Large potential for flexible digital circuits in (passive) RFID/NFC chips, integrated in paper or plastics
- Examples:
  - Flexible labels
  - Intelligent packages
  - Smart blisters
  - Electronic medical patches



#### Flexible electronics on plastics Digital circuits

- Circuits that have already been fabricated:
  - NFC transponder
  - 8-bit microprocessor with limited instruction set



CROSSING, 2019, Darmstadt, Germany

#### Flexible electronics on plastics Transistor technology

- Several thin-film transistor (TFT) technologies exist
  - Amorphous silicon TFTs
  - Low-temperature polycrystalline silicon TFTs
  - Organic TFTs
  - Amorphous metal-oxide TFTs
- Amorphous metal-oxide TFTs show the best combination of high performance and low processing cost
- a-IGZO (amorphous indium gallium zinc oxide) is used as a semiconductor

### Flexible electronics on plastics Comparison with silicon transistors

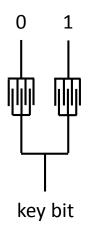
	silicon (10 nm)	a-IGZO (5 μm)	
Core supply voltage	0.7 V	5-10 V	Higher power consumption
Charge carrier mobility	500-1500 cm <sup>2</sup> /Vs	2-20 cm <sup>2</sup> /Vs	Lower performance
Transistor density	~ 45 mio per mm²	10 <sup>3</sup> -10 <sup>4</sup> per cm <sup>2</sup>	Larger area
Semiconductor type	n-type and p-type	only n-type	Unipolar logic
Cost per 1000 transistors	> 0.3 USD	> 0.01 USD	Lower cost
Flexible?	no	yes	Bendable, stretchable

CROSSING, 2019, Darmstadt, Germany

#### Flexible electronics on plastics Non-volatile memory

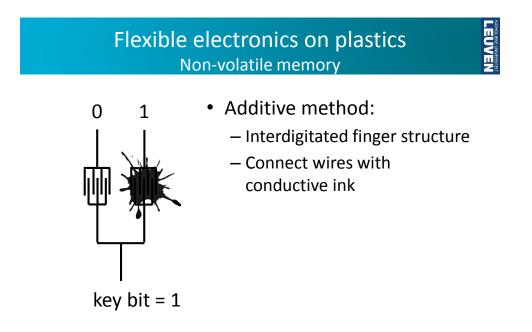
- We need non-volatile memory to store values, such as cryptographic keys, after fabrication
- On plastic substrates, electrically readable/writable memory (e.g. flash) does not exist
- Two one-time programmable storage mechanisms are used:
  - Additive method: connect wires with conductive ink
  - Modificative method: cut wires with a laser

### Flexible electronics on plastics Non-volatile memory

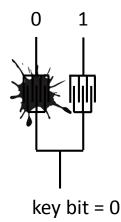


- Additive method:
  - Interdigitated finger structure
  - Connect wires with conductive ink

CROSSING, 2019, Darmstadt, Germany

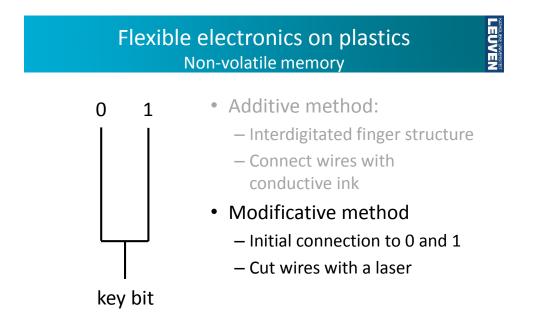


### Flexible electronics on plastics Non-volatile memory

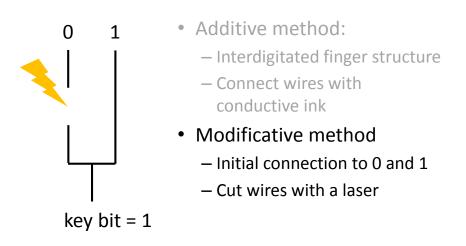


- Additive method:
  - Interdigitated finger structure
  - Connect wires with conductive ink

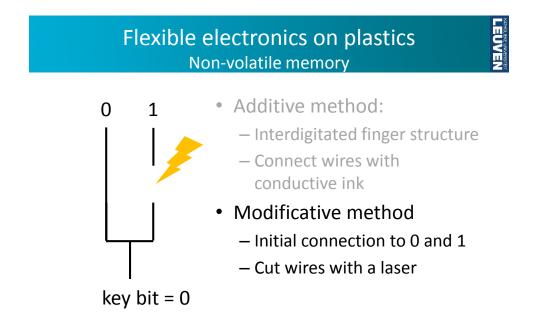
CROSSING, 2019, Darmstadt, Germany



### Flexible electronics on plastics Non-volatile memory



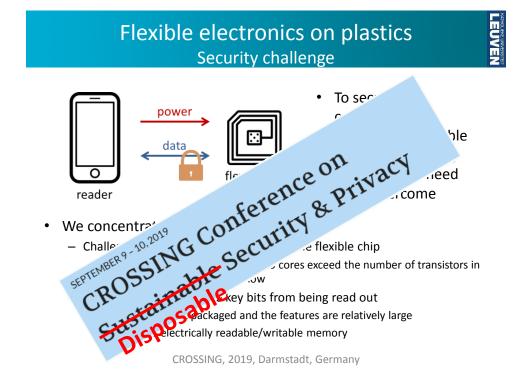
CROSSING, 2019, Darmstadt, Germany



### Flexible electronics on plastics Security challenge



- To secure the communication between the flexible tag and the reader, many hurdles need to be overcome
- We concentrate on two challenges:
  - Challenge #1: integrate crypto cores in the flexible chip
    - The number of transistors in crypto cores exceed the number of transistors in flexible chips reported up to now
  - Challenge #2: prevent the key bits from being read out
    - The chips are not packaged and the features are relatively large
    - There is no electrically readable/writable memory



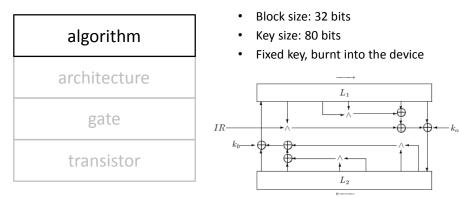
#### Challenge #1: crypto core on plastics Design choices

algorithm architecture gate transistor

CROSSING, 2019, Darmstadt, Germany

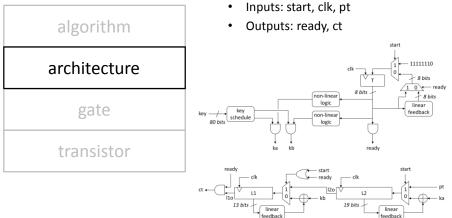


#### KTANTAN32 [1]



[1] C. De Cannière, O. Dunkelman, M. Knežević, *KATAN and KTANTAN—a family of small and efficient hardware-oriented block ciphers*, CHES 2009, p. 272-288.

#### Challenge #1: crypto core on plastics **Design choices**

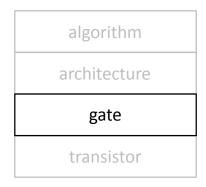


Serial architecture

Inputs: start, clk, pt

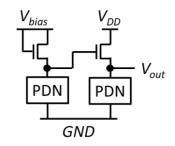
CROSSING, 2019, Darmstadt, Germany

#### Challenge #1: crypto core on plastics **Design choices**



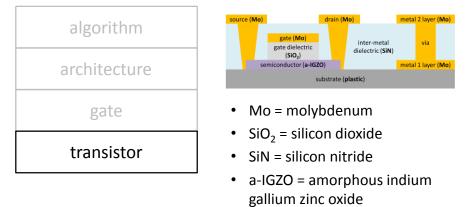
#### pseudo-CMOS logic

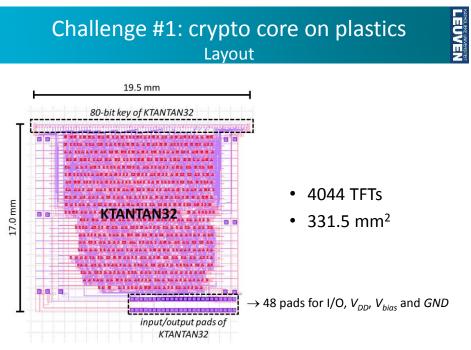
- 6 TFTs in one NAND gate
- Pull-Down Network (PDN) repeated
- $V_{bias} > V_{DD} + 2V_T \rightarrow rail-to-rail output$



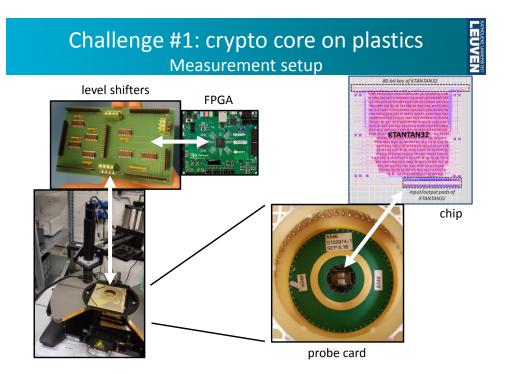
#### Challenge #1: crypto core on plastics Design choices

#### a-IGZO semiconductor



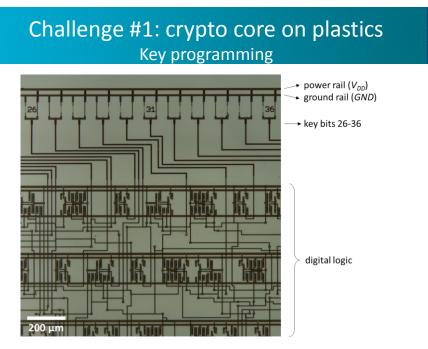


CROSSING, 2019, Darmstadt, Germany



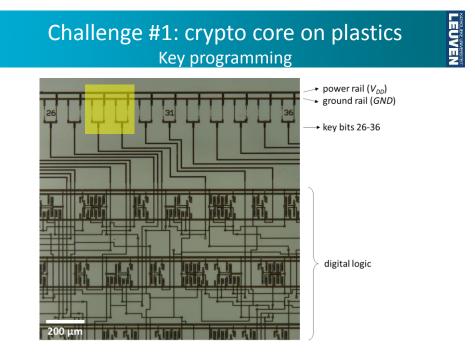
#### Challenge #1: crypto core on plastics Measurement results

- Fixed 80-bit key: 07C1F07C1F07C1F07C1F (hex)
- 1000 plaintexts automatically applied
- 1000 correct ciphertexts for:
  - $V_{DD}$  = 10 V and  $V_{bias}$  = 15 V
  - $V_{DD}$  = 11 V and  $V_{bias}$  = 16.5 V
- Maximum clock frequency = 10 kHz
- Number of cycles:
  - 32 (for shifting in the plaintext)
  - 254 (for the actual encryption)
  - 32 (for shifting out the ciphertext)
- Total latency = 31.8 ms

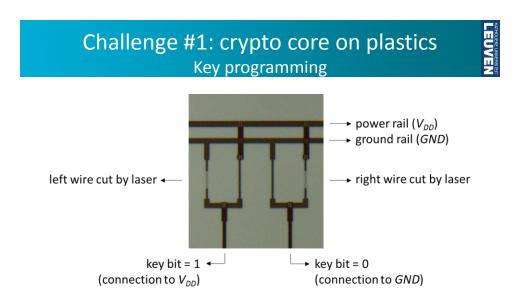


EUVE

CROSSING, 2019, Darmstadt, Germany

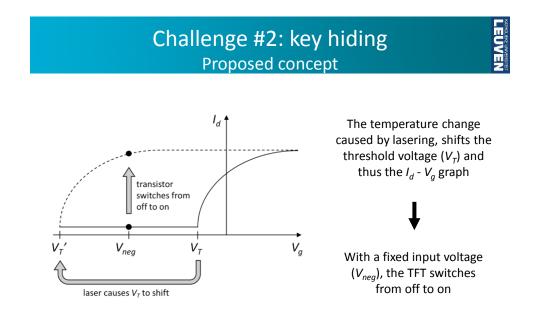


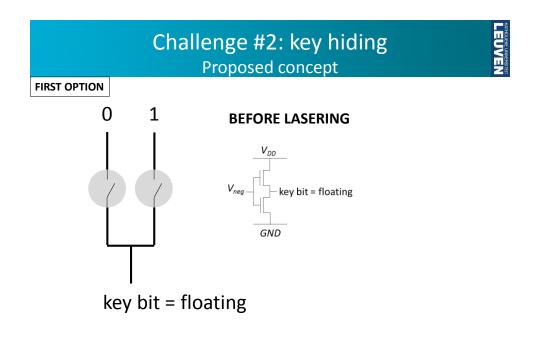
CROSSING, 2019, Darmstadt, Germany

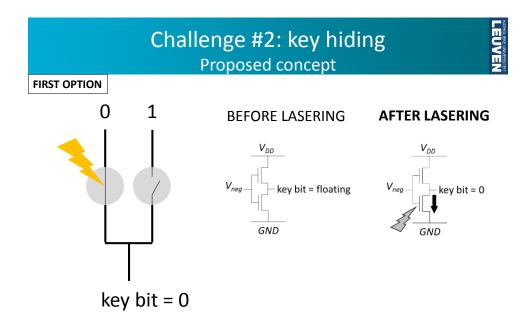


PROBLEM: The key bits can easily be read out using a microscope

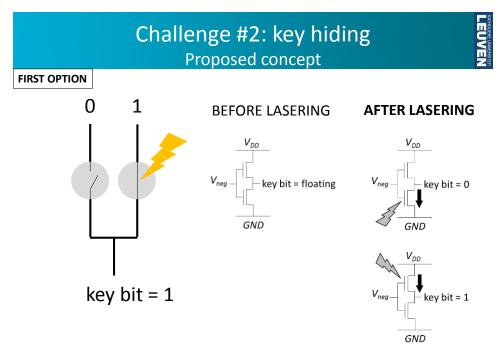
CROSSING, 2019, Darmstadt, Germany

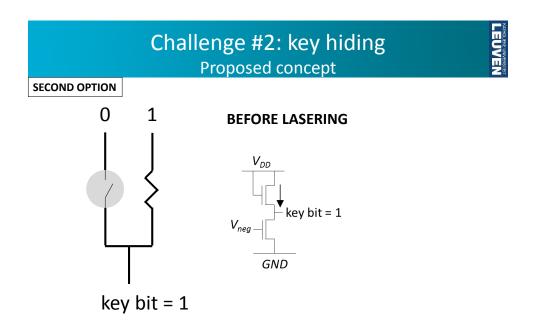




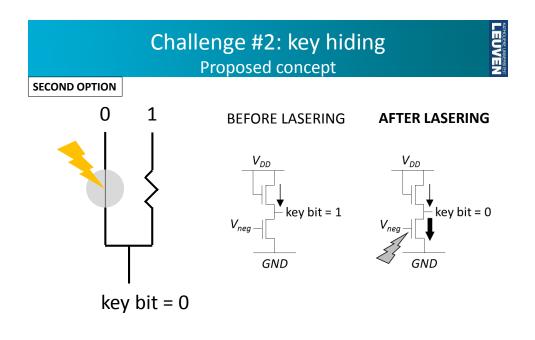


CROSSING, 2019, Darmstadt, Germany





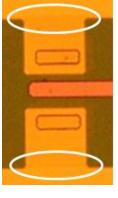
CROSSING, 2019, Darmstadt, Germany



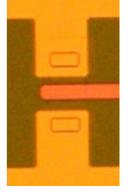
CROSSING, 2019, Darmstadt, Germany

### Challenge #2: key hiding Experimental validation

#### TFT microscope images







PROBLEM: The difference is visible between a TFT that has been lasered and a TFT that has not been lasered

not lasered

#### Challenge #2: key hiding **Experimental validation**

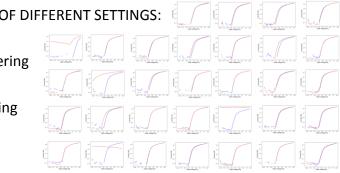
#### SOLUTION:

Apply different settings of the laser to cause different  $V_{\tau}$  shifts that cannot be visually distinguished

EXPLORATION OF DIFFERENT SETTINGS:

- Blue: before lasering
- Red:

after lasering



CROSSING, 2019, Darmstadt, Germany

#### Challenge #2: key hiding Experimental validation

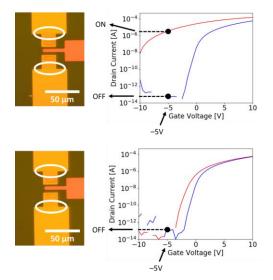
SOLUTION:

Apply different settings of the laser to cause different  $V_{\tau}$  shifts that cannot be visually distinguished

EXPLORATION OF DIFFERENT SETTINGS: Blue: • before lasering Red: after lasering

CROSSING, 2019, Darmstadt, Germany

### Challenge #2: key hiding Experimental validation



#### SOLUTION:

Apply different settings of the laser to cause different  $V_{\tau}$  shifts that cannot be visually distinguished:

- Setting 1 (top image): attenuation of 45 dB in low energy mode; one pulse applied
- Setting 2 (bottom image): attenuation of 35 dB in low energy mode; two pulses applied

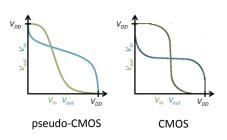
CROSSING, 2019, Darmstadt, Germany

#### Challenge #2: key hiding Possible alternative solution

- Additive method instead of modificative method:
  - Add ink at the top and the bottom of the chip
  - The ink should be:
    - Non-conductive
    - Non-transparent
    - Insoluble

# **Remaining challenges**

- Physically Unclonable Functions (PUFs) on plastics
  - Digital circuits continue to operate correctly when they are bended or stretched, but PUFs might not produce a reliable unique output
- True Random Number Generators (TRNGs) on plastics
  - The slope of the inputoutput characteristic of pseudo-CMOS gates is less steep compared to CMOS gates, so the design of TRNGs needs to be revisited



CROSSING, 2019, Darmstadt, Germany

